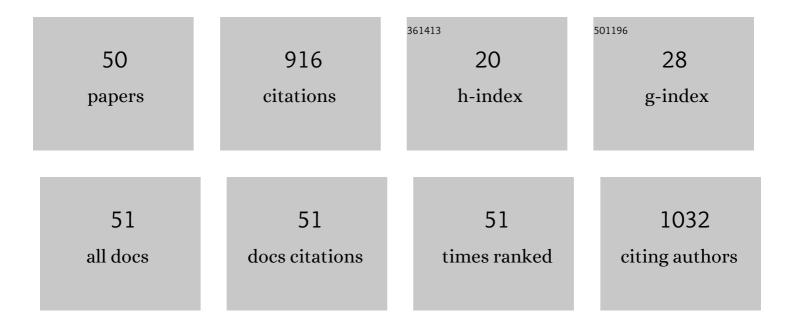
## Da-Ren Hang

List of Publications by Year in descending order

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#	Article	IF	CITATIONS
1	Rational design of hetero-dimensional C-ZnO/MoS2 nanocomposite anchored on 3D mesoporous carbon framework towards synergistically enhanced stability and efficient visible-light-driven photocatalytic activity. Chemosphere, 2021, 266, 129148.	8.2	28
2	Two-dimensional molybdenum trioxide nanoflakes wrapped with interlayer-expanded molybdenum disulfide nanosheets: Superior performances in supercapacitive energy storage and visible-light-driven photocatalysis. International Journal of Hydrogen Energy, 2021, 46, 34663-34678.	7.1	6
3	2D CTAB-MoSe2 Nanosheets and 0D MoSe2 Quantum Dots: Facile Top-Down Preparations and Their Peroxidase-Like Catalytic Activity for Colorimetric Detection of Hydrogen Peroxide. Nanomaterials, 2020, 10, 2045.	4.1	20
4	Facile Bottom-up Preparation of WS2-Based Water-Soluble Quantum Dots as Luminescent Probes for Hydrogen Peroxide and Glucose. Nanoscale Research Letters, 2019, 14, 271.	5.7	28
5	Comparative Photothermal Performance among Various Subâ€Stoichiometric 2D Oxygenâ€Deficient Molybdenum Oxide Nanoflakes and Inâ€Vivo Toxicity. Chemistry - A European Journal, 2018, 24, 7417-7427.	3.3	23
6	Two dimensional α-MoO 3-x nanoflakes as bare eye probe for hydrogen peroxide in biological fluids. Analytica Chimica Acta, 2018, 1015, 58-65.	5.4	27
7	Glucose oxidase assisted visual detection of glucose using oxygen deficient α-MoO3-x nanoflakes. Mikrochimica Acta, 2018, 185, 65.	5.0	21
8	Facile and Costâ€Efficient Synthesis of Quasiâ€0D/2D ZnO/MoS <sub>2</sub> Nanocomposites for Highly Enhanced Visibleâ€Lightâ€Driven Photocatalytic Degradation of Organic Pollutants and Antibiotics. Chemistry - A European Journal, 2018, 24, 9305-9315.	3.3	61
9	Rapid naked eye detection of alkaline phosphatase using α-MoO3-x nano-flakes. Sensors and Actuators B: Chemical, 2018, 254, 514-518.	7.8	23
10	Landau-level mixing, floating-up extended states, and scaling behavior in a GaAs-based two-dimensional electron system containing self-assembled InAs dots. Semiconductor Science and Technology, 2017, 32, 085011.	2.0	0
11	Synthesis and characterization of two-dimensional carbon dots decorated with molybdenum oxide nanoflakes with various phases. New Journal of Chemistry, 2016, 40, 8954-8960.	2.8	9
12	Enhanced Photocatalytic Performance of ZnO Nanorods Coupled by Twoâ€Dimensional αâ€MoO <sub>3</sub> Nanoflakes under UV and Visible Light Irradiation. Chemistry - A European Journal, 2016, 22, 12777-12784.	3.3	27
13	Full Solutionâ€Processed Synthesis and Mechanisms of a Recyclable and Bifunctional Au/ZnO Plasmonic Platform for Enhanced UV/Vis Photocatalysis and Optical Properties. Chemistry - A European Journal, 2016, 22, 14950-14961.	3.3	29
14	Controlling band gap and refractive index in dopant-free α-Fe2O3 films. Electronic Materials Letters, 2015, 11, 13-23.	2.2	21
15	Resonant Raman scattering and photoluminescent properties of nonpolar <i>a</i> -plane ZnO thin film on LiGaO <sub>2</sub> substrate. Applied Physics Express, 2014, 7, 041101.	2.4	10
16	Annealing effects on the optical and morphological properties of ZnO nanorods on AZO substrate by using aqueous solution method at low temperature. Nanoscale Research Letters, 2014, 9, 632.	5.7	50
17	Optical characteristics of nonpolara-plane ZnO thin film on (010) LiGaO2substrate. Semiconductor Science and Technology, 2014, 29, 085004.	2.0	14
18	Room-temperature violet luminescence and ultraviolet photodetection of Sb-doped ZnO/Al-doped ZnO homojunction array. Nanoscale Research Letters, 2013, 8, 313.	5.7	24

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19	Fabrication and photoresponse of ZnO nanowires/CuO coaxial heterojunction. Nanoscale Research Letters, 2013, 8, 387.	5.7	28
20	On the coexistence of localization and semiclassical transport in the low-field quantum Hall effect. Physica E: Low-Dimensional Systems and Nanostructures, 2012, 44, 1558-1561.	2.7	2
21	Growth and Characterization of Vertically Aligned Nonpolar [11Ì00] Orientation ZnO Nanostructures on (100) γ-LiAlO <sub>2</sub> Substrate. Crystal Growth and Design, 2012, 12, 6208-6214.	3.0	9
22	Nonpolar a-plane ZnO growth and nucleation mechanism on (100) (La, Sr)(Al, Ta)O3 substrate. Materials Chemistry and Physics, 2011, 125, 791-795.	4.0	15
23	Growth of nonpolar m-plane GaN epitaxial film on a lattice-matched (100) β-LiGaO2 substrate by chemical vapor deposition. Thin Solid Films, 2011, 519, 5066-5069.	1.8	21
24	Epitaxial growth of nonpolar m-plane ZnO (10–10) on large-size LiGaO2 (100) substrates. Thin Solid Films, 2011, 519, 3627-3631.	1.8	28
25	MOVPE growth and properties of non-polar InGaN/GaN multiple quantum wells on Î <sup>3</sup> -LiAlO2 substrates. Journal of Crystal Growth, 2010, 312, 1329-1333.	1.5	8
26	Growth and characterizations of nonpolar [11â^'20] ZnO on [100] (La,Sr)(Al,Ta)O3 substrate by chemical vapor deposition. Journal of Crystal Growth, 2010, 312, 1170-1174.	1.5	15
27	Growth of freeâ€standing nonâ€polar GaN on (100) γâ€LiAlO <sub>2</sub> substrates by hydride vapor phase epitaxy. Physica Status Solidi C: Current Topics in Solid State Physics, 2010, 7, 1764-1766.	0.8	5
28	Fabrication and characterization of quantum Hall devices for the resistance standard at CMS. , 2010, , $\cdot$		0
29	Improved quality of nonpolar m-plane GaN [101Â <sup>-</sup> 0] on LiAlO2 substrate using a modified chemical vapor deposition. Journal of Applied Physics, 2010, 107, 013502.	2.5	12
30	Probing semiclassical magneto-oscillations in the low-field quantum Hall effect. Physical Review B, 2009, 80, .	3.2	10
31	Growth and characterization of m-plane GaN-based layers on LiAlO2 (100) grown by MOVPE. Journal of Crystal Growth, 2009, 311, 452-455.	1.5	18
32	Optical characteristics of m-plane InGaN/GaN multiple quantum well grown on LiAlO2 (100) by MOVPE. Journal of Crystal Growth, 2009, 311, 2919-2922.	1.5	8
33	Crystal Growth of Nonpolar m-Plane ZnO on a Lattice-Matched (100) Î <sup>3</sup> -LiAlO <sub>2</sub> Substrate. Crystal Growth and Design, 2009, 9, 2073-2078.	3.0	31
34	Optical Investigations of Non-polar \$bm{m}\$-plane InGaN/GaN Multiple Quantum Wells Grown on LiAlO\$_{2}\$ (100) by Using MOVPE. Journal of the Korean Physical Society, 2009, 55, 250-254.	0.7	4
35	An experimental study on Γ(2) modular symmetry in the quantum Hall system with a small spin splitting. Journal of Physics Condensed Matter, 2007, 19, 026205.	1.8	9
36	Crystal growth and properties of LiAlO2 and nonpolar GaN on LiAlO2 substrate. Journal of Applied Physics, 2007, 101, 103106.	2.5	33

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37	From semiclassical transport to quantum Hall effect under low-field Landau quantization. Solid State Communications, 2007, 141, 17-21.	1.9	14
38	Two-subband-populated AlGaNâ^•GaN heterostructures probed by electrically detected and microwave-modulated magnetotransport measurements. Applied Physics Letters, 2006, 89, 092116.	3.3	12
39	Effects of Zeeman spin splitting on the modular symmetry in the quantum Hall effect. Microelectronics Journal, 2005, 36, 469-471.	2.0	7
40	Large effective mass enhancement of the InAs1â^'xNx alloys in the dilute limit probed by Shubnikov-de Haas oscillations. Physica E: Low-Dimensional Systems and Nanostructures, 2004, 22, 308-311.	2.7	8
41	Conventional and microwave-modulated Shubnikov–de Haas oscillations in GaN electron systems. Physica E: Low-Dimensional Systems and Nanostructures, 2004, 21, 631-635.	2.7	1
42	Microwave-modulated Shubnikov–de Haas oscillations in a two-dimensional GaN electron gas. Physica E: Low-Dimensional Systems and Nanostructures, 2004, 22, 578-581.	2.7	2
43	Microwave-aided transport measurements on high-density two-dimensional electron systems confined at AlGaN/GaN heterointerfaces. Physica Status Solidi C: Current Topics in Solid State Physics, 2003, 0, 2323-2326.	0.8	0
44	Electrically detected and microwave-modulated Shubnikov–de Haas oscillations in an Al0.4Ga0.6N/GaN heterostructure. Journal of Applied Physics, 2003, 93, 2055-2058.	2.5	21
45	Transport in a gated Al0.18Ga0.82N/GaN electron system. Journal of Applied Physics, 2003, 94, 3181-3184.	2.5	32
46	Persistent photoconductivity in InxAlyGa1â^'xâ^'yN quaternary alloys. Applied Physics Letters, 2003, 82, 1884-1886.	3.3	14
47	ShubnikovÂde Haas oscillations of two-dimensional electron gas in an InAsN/InGaAs single quantum well. Semiconductor Science and Technology, 2002, 17, 999-1003.	2.0	10
48	Effective mass of two-dimensional electron gas in an Al0.2Ga0.8N/GaN heterojunction. Applied Physics Letters, 2001, 79, 66-68.	3.3	34
49	AlxGa1â^'xN/GaN band offsets determined by deep-level emission. Journal of Applied Physics, 2001, 90, 1887-1890.	2.5	76
50	Positive and negative persistent photoconductivity in a two-side-dopedIn0.53Ga0.47As/In0.52Al0.48Asquantum well. Physical Review B, 1999, 60, 13318-13321.	3.2	7